Company
National Semiconductor



#### **URL for Additional Information**

http://www.national.com/quality/green/

Contact	Title	Phone	Email
Gloria Gordon	Engineering Project Manager	1-408-721-8435	Green.project@nsc.com

Part Number	MSL Rating	Peak Body Temp C	MaxTime (Sec)	Cycles
TP3420AV309	3	220	30	4

Document Date	ontains Lead(Pb) and is NOT European RoHS Complian	Weight (mg)	Unit Type	
5-May-2007	NOT China RoHS Compliant	676.000	Each	

Hoi	Homogeneous Material Composition Declaration for Electronic Products							
Item	Weight (mg)	Component	CAS#	Weight (mg)	Item-ppm	Part-ppm		
Plastic	452.200	452.200 SiO2 60676-86-0 339.150 750,0		750,000	501,701			
		Epoxy Resin	25928-94-3	104.910	232,000	155,193		
		Sb2O3	1309-64-4	5.426	12,000	8,027		
		Brominated Epoxy	40039-93-8	2.713	6,000	4,014		
Leadframe	189.540	Cu	7440-50-8	184.707	974,500	273,235		
		Fe	7439-89-6	4.549	24,000	6,729		
		Zn	7440-66-6	0.227	1,200	336		
		P	7723-14-0	0.057	300	84		
Ext. LeadFinish	18.080	Sn	7440-31-5	15.368	850,000	22,734		
		Pb	7439-92-1	2.712	150,000	4,012		
Chip	12.580	Si	7440-21-3	12.505	994,000	18,498		
		Al	7429-90-5	0.075	6,000	112		
Int. LeadFinish	1.400	Ag	7440-22-4	1.400	1,000,000	2,071		
Die Attach	1.280	Ag	7440-22-4	0.960	750,000	1,420		
		Epoxy Resin	25928-94-3	0.320	250,000	473		
Wires	0.920	Au	7440-57-5	0.920	1,000,000	1,361		

**Note:** The device content disclosed herewith is approximate and is based on engineering estimates only. It has not been verified through analytical testing. Additionally, the following should be noted:

- 1. One or more dopant materials may be present in the silicon die at sub-ppm levels to provide semiconductor properties.
- 2. Epoxy resin components listed are generic and may or may not be the specific compound used, which is considered proprietary.

#### **RoHS Material Composition Declaration**

RoHS Directive 2002/95/EC RoHS Definition: Quantity limit of 0.1% by mass (1000 PPM) in homogeneous material for: Lead (Pb), Mercury, Hexavalent Chromium, Polybrominated Biphenyls (PBB), Polybrominated Diphenyl Ethers (PBDE) and quantity limit of 0.01% by mass (100 PPM) of homogeneous material for Cadmium

Subject to the limitations below, National Semiconductor Corporation ("National") certifies the following information as of the document date.

- 1. National products with lead-free solder comply with the European Union's Directive on the Restriction of the Use of Hazardous Substances 2002/95/EC ("RoHS"). These products do not contain homogeneous materials with Joint Industry Guide (JIG) -101 Level A materials above Level A threshold levels, except lead in RoHS exempt applications 5, 7a and 7c.
- 2. National products with lead-containing solder do not comply with RoHS, because they contain lead in a non-exempt application. These products do not contain other RoHS restricted substances or homogeneous materials with JIG-101 Level A materials above Level A threshold levels, except lead in solder and RoHS exempt applications 5, 7a and 7c.
- 3. National products are manufactured in conformance with National specifications (SC) CSP-9-111C1 Supplier Environmental Requirements for Materials and Products and (SC) CSP-9-111S2 National's List of Banned and Reportable Substances, which are available at <a href="https://www.national.com/quality/green/">www.national.com/quality/green/</a>.
- 4. National products do not contain and are not manufactured with ozone depleting substances subject to The Montreal Protocol on Substances that Deplete the Ozone Layer and U.S. Clean Air Act, Title VI.

National has taken commercially reasonable steps to provide representative and accurate information but may not have independently verified information provided by others or conducted testing or chemical analysis on incoming materials and chemicals. Information provided in this document is derived from default values associated with internal process information and may not be representative of all or actual materials used in the product (e.g. the default may indicate a particular material, while an equivalent compliant material from the same or alternate supplier was actually used). Material concentrations are the maximum expected concentration of the substances in the device and may not represent the actual concentration. National and National suppliers consider certain limited information to be confidential and thus CAS numbers and other limited information may not be available for release. National's standard warranty and limitation of liability provisions of National's Standard Terms and Conditions of Sale apply to any issues arising out of or in connection with the information provided herein unless otherwise provided by a written contract signed by both parties.

NATIONAL ACCEPTS NO DUTY TO NOTIFY USERS OF THIS DECLARATION OF UPDATES OR CHANGES TO THIS DECLARATION.

GATild

Gerry Fields
Vice President Quality

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### **Banned Substance Monitoring**

Part Number	Document Date		
TP3420AV309	5-May-2007		

# Contains Lead(Pb) and is NOT European RoHS Compliant.

### NOT China RoHS Compliant

Use	Material	Cd	CrVI	Pb	Hg	PBB	PBDE	Ref #
Device	CHIP	<1	<1	<1	<1	<1	<1	1000
	COMPOUND							
	DIEATTACH							
	EXTLF	<2	<2	149000	<2	NA	NA	56
	FRAME	<100	<1000	<1000	<1000	<1000	<1000	9990
	WIRE	<2	<5	<5	<1	<10	<10	75

<sup>\*</sup> Cd: Cadmium, CrVI: Hexavalent Chromium, Pb: Lead, Hg: Mercury, ND: Not Detected

<sup>\*</sup> Unless otherwise noted, units are in PPM (parts-per-million)

Ref #	3rd Party Analysis (available upon request, subject to a non-disclosure agreement)
1000	Analysis on 04/17/2007 by Balazs Analytical Services-Freemont CA per Report# 07-01051-07
56	Analysis on 04/27/2007 by SGS per Report# LPCI/07440/07
75	Analysis on 05/16/2007 by ALS per Report# ATJB/3490BS/2007
9990	Analysis pending

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# 美国国家半导体



## 《电子信息产品污染控制管理办法》的声明

"Electronic Information Products Pollution Control Measures" Statement

#### China RoHS Declaration

产品名称	TP3420AV309
Product Name	11 0420/(1000)

		有毒有害物 <b>质或元素</b> Toxic and harmful substances or elements					
部件名称 Part	<b>铅</b> (Pb)	汞 (Hg)	<b>镉</b> (Cd)	六价 <b>铬</b> (Cr6+)	多 <b>溴联苯</b> (PBB)	多 <b>溴二苯醚</b> (PBDE)	
集成 <b>电路</b> Integrated Circuit	X	0	0	0	0	0	

〇:表示该有毒有害物质在该部件所有均质材料中的含量均在SJ/T 11363-2006标准规定的限量要求以下。

**O**: Indicates that this hazardous substance contained in all homogeneous materials of this part is below the limit requirement in SJ/T 11363-2006.

X:表示该有毒有害物质至少在该部件的某一均质材料中的含量超出 SJ/T 11363-2006 标准规定的限量要求。

**X**: Indicates that this hazardous substance contained in at least one of the homogeneous materials of this part is above the limit requirement in SJ/T 11363-2006.

# 美国国家半**导体的产品不会含有镉、汞、六价铬、多溴联苯(PBB)** 和二苯**醚(PBDE)**。

National Semiconductor's products will not contain cadmium, mercury, hexavalent chromium, polybrominated biphenyls (PBBs) and diphenyl ether (PBDE).



**环保使用期限(epup)** 是指以符号在**这里展出. 环保使用期限(epup)** 的有效期只有当**产品使用范围以内的数据表中的规格.** 

The Environmental Protection Use Period (EPUP) is defined by the symbol shown here. The Environmental Protection Use Period (EPUP) is valid only when product is used within the limits of the data sheet specifications.